

***IN THE UNITED STATES PATENT AND TRADEMARK OFFICE***

Applicants: Yasuhiro OKAMOTO et al.  
Title: FIELD-EFFECT TRANSISTOR HAVING GROUP III  
NITRIDE ELECTRODE STRUCTURE  
Appl. No.: 10/538,739  
Filing Date: 11/9/2005  
Examiner: Sarah Kate Salerno  
Art Unit: 2814  
Confirmation No.: 7288

**AMENDMENT AND REPLY UNDER 37 C.F.R. 1.116**

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

This communication is responsive to the Final Office Action dated November 16, 2010, concerning the above-referenced patent application.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this document.

**Remarks/Arguments** begin on page 6 of this document.

Please amend the application as follows: